



UKAEA-CCFE-PR(19)40

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# CALANIE: anisotropic elastic correction to the total energy, to mitigate the effect of periodic boundary conditions

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## CALANIE: anisotropic elastic correction to the total energy, to mitigate the effect of periodic boundary conditions

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This is a preprint of a paper submitted for publication in Computer Physics Communications

### CALANIE: anisotropic elastic correction to the total energy, to mitigate the effect of periodic boundary conditions

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#### Abstract

CALANIE (CALculation of ANIsotropic Elastic energy) program evaluates an elastic interaction correction to the total energy of a localized object, for example a defect in a solid material simulated using an *ab initio* or molecular statics approach, resulting from the use of periodic boundary conditions. The correction, computed using a fully elastically anisotropic Green's function formalism, arises from the elastic interaction between a defect and its own periodically translated images. The field of elastic displacements produced by the defect is described in the elastic dipole approximation. Applications of the method are illustrated by two case studies, one involving an *ab initio* investigation of point defects and vacancy migration in FCC gold, and another a molecular statics simulation of a dislocation loop. We investigate the convergence of the method as a function of the simulation cell size, and note the particular significance of elastic correction in the limit where the size of the defect is comparable with the size of the simulation cell.

*Keywords:* Point defects, elastic dipole tensor, anisotropic elasticity, periodic boundary conditions, *ab initio* calculations

Preprint submitted to Computer Physics Communications

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#### PROGRAM SUMMARY

<sup>2</sup> Manuscript Title: CALANIE: anisotropic elastic correction to the total energy,

- <sup>3</sup> to mitigate the effect of periodic boundary conditions
- 4 Authors: Pui-Wai Ma, S. L. Dudarev
- <sup>5</sup> Program Title: CALANIE, version 2.0
- 6 Journal Reference:

1

- 7 Catalogue identifier:
- <sup>8</sup> Licensing provisions: Apache License, Version 2.0
- 9 Programming language: C/C++
- <sup>10</sup> Computer: Any computer with C/C++ compiler
- <sup>11</sup> Operating system: Linux, Unix, Windows
- <sup>12</sup> *RAM:* 15MB
- <sup>13</sup> Number of processors used: 1
- 14 Supplementary material:
- <sup>15</sup> Keywords: Defects, dipole tensor, elastic correction, anisotropy elasticity, ab initio
- <sup>16</sup> calculations, periodic boundary conditions
- 17 Classification: 7.1
- 18 External routines/libraries:
- 19 Subprograms used:
- 20 Nature of problem:

Periodic boundary conditions (PBCs) are often used in the context of *ab initio* 21 and interatomic potential based atomic scale simulations. A localized defect in 22 a crystalline material, simulated using PBCs, interacts elastically with its own 23 periodically translated images, and this gives rise to a systematic error in the 24 computed defect formation or migration energy. Evaluating the correction to the 25 total energy resulting from effects of elastic interaction between a defect and its 26 periodic images, to alleviate the effect of PBCs, is an essential aspect of any accu-27 rate calculation of the energy of a defect performed using PBCs. 28

29

30 Solution method:

The energy of interaction between a localized defect and its periodically translated 31 images is computed in the linear elasticity approximation. In this approximation, 32 the energy of elastic interaction is expressed analytically in terms of the elastic 33 dipole tensor of the defect and elastic Green's function. Elements of the dipole 34 tensor are computed as a part of the simulation evaluating the formation energy of 35 the defect. Elastic Green's function and its first and second derivatives are com-36 puted numerically from the elastic constants of the material. The method and the 37 corresponding numerical procedures are implemented in the CALANIE computer 38 program. The program evaluates matrix elements of the elastic dipole tensor of a 39 localized defect and the elastic correction to the total energy arising from the use 40

of periodic boundary conditions. 41

42

*Restrictions:* 43

The approach assumes the validity of the linear elasticity approximation. This 44 limits the accuracy of evaluation of the elastic correction, which becomes less pre-45 46

cise if the size of the defect is comparable with the size of the simulation cell.

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Unusual features: 48

An open source code, containing full detail of the relevant theoretical concepts, 49 algorithms and numerical implementation. 50

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*Running time:* A typical calculation takes several minutes. 52

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54

#### 1. Introduction 55

Mechanical deformation or irradiation by energetic particles produce de-56 fects in a crystalline material, such as dislocations, dislocation loops, voids, 57 and Frenkel pairs [1, 2, 3, 4]. Defect structures evolve under the effect of ex-58 ternal stress and temperature. Defects migrate, segregate and agglomerate as 59 a result of elastic interaction, mediated by lattice deformations [5, 6, 7, 8, 9]. 60 Evolution of defect structures changes mechanical and physical properties of 61 the material [10]. 62

Electronic and atomic scale simulations are indispensable numerical tools 63 that help understand the fundamental laws driving microstructure evolution 64 and its effect on mechanical and physical properties of the materials. Ab ini-65 tio density function theory (DFT) calculations [11, 12] are commonly used for 66 computing the formation and migration energies of small defects. The energy 67 of formation of a defect at equilibrium determines the relative probability of 68 its occurrence, whereas the energy of migration determines the rate of evolu-60 tion of a defect structure. Molecular dynamics [2, 3] and kinetic Monte Carlo 70 [13, 14, 15] simulations provide information about the rates and pathways of 71 relaxation processes characterizing complex configurations of defects. 72

To avoid considering surface effects, simulations are often performed us-73 ing periodic boundary conditions (PBCs). Through periodic boundary con-74 ditions, a spatially localized defect situated in a simulation cell interacts 75 elastically with an infinite number of its own images situated in periodically 76

translated simulation cells [6, 7, 8, 9]. Since elastic fields effectively have infi-77 nite range, and the energy  $E_{el}$  of elastic interaction between any two defects 78 varies as the inverse cube of distance R between the defects  $E_{el} \sim R^{-3}$  [8], 79 if a relatively small cell is used in a simulation, the elastic energy of interac-80 tion between a defect and its periodic images can be substantial. This can 81 affect the accuracy of calculations performed using PBCs and make the total 82 energy data strongly dependent on the cell size. Although in principle the 83 issue can be circumvented using a larger simulation cell, in practice this may 84 not necessarily be a realistic option because of the limitations imposed by 85 the available computational resources or numerical algorithms. For example, 86 in a conventional DFT calculation, the simulation cell size is still limited to 87 a few hundred atoms. 88

A possible way forward is to introduce an elastic correction to the calculated formation energy. A first order correction, in the linear elasticity far field approximation, can be derived using the elastic dipole tensor formalism [6, 7, 8, 9], which only requires knowing the elements of elastic dipole tensor  $P_{ij}$  of the defect and the elastic constants tensor  $C_{ijkl}$  of specific material. This information can be readily derived from the same DFT or molecular statics calculation.

An elastic dipole tensor fully defines the elastic field produced by a defect 96 in a material [16]. The strain field associated with a localized defect can 97 be expressed in an explicit analytical manner in terms of the dipole tensor. 98 From the dipole tensor it is also possible to evaluate the relaxation volume 99 tensor of the defect [17]. By considering a defect as a compound object 100 characterized by its dipole tensor, it is possible to formulate a continuum 101 model spanning the spatial scale many orders of magnitude larger than an 102 atomistic simulation. In addition, the notion of the dipole tensor enables 103 treating interactions between defects. A dipole tensor can be defined for 104 an arbitrarily large configuration of defects, for example the entire defect 105 structure created in a collision cascade simulation can be described by a 106 dipole tensor, enabling extending the treatment to a macroscopic scale [17]. 107

In previous studies, we derived analytical equations for treating the elastic fields of defects in a simulation cell using periodic boundary conditions [8]. We have also derived equations for evaluating the elastic correction to the energy of a localized defect [9], and implemented them in our program CALANIE. It is appropriate to make this code, suitable for evaluating the elastic correction to the total energy, and for calculating the elastic dipole tensor of a defect in a simulation cell, available as an open source computer program. Full numerical and algorithmic aspects of the code are describedbelow.

In what follows we review our theory and explain the meaning of various 117 equations. We also discuss the details of the numerical implementation of the 118 method, followed by the details of the compilation procedure, and the format 119 of input and output files. We give two examples illustrating applications of 120 the code. The first example involves *ab initio* calculations of properties of 121 point defects and vacancy migration in FCC gold. This example illustrates 122 the applicability of CALANIE to both equilibrium and non-equilibrium con-123 figurations. The second example illustrates molecular statics calculations 124 of mecoscopic size dislocation loops. We investigate the convergence of the 125 dipole tensor and the formation energy of defects as functions of the sim-126 ulation box size, and the significance of applying elastic correction to the 127 formation energy in the limit where the simulation cell is relatively small. 128

#### 129 2. Theory

#### 130 2.1. Elastic dipole tensor

<sup>131</sup> In continuum elasticity theory, the elastic strain energy of a defect in an <sup>132</sup> infinite medium is defined as a volume integral over the entire space:

$$E_D = \frac{1}{2} \int_V \sigma_{ij}(\mathbf{r}) \epsilon_{ij}(\mathbf{r}) dV, \qquad (1)$$

where  $\epsilon_{ij}$  and  $\sigma_{ij}$  are the elastic strain and stress fields. Assuming the validity of the linear elasticity approximation, we write  $\sigma_{ij} = C_{ijkl}\epsilon_{kl}$ , where  $C_{ijkl}$  is the elastic constant tensor of rank four. The above equation now acquires the form

$$E_D = \frac{1}{2} \int_V C_{ijkl} \epsilon_{kl}(\mathbf{r}) \epsilon_{ij}(\mathbf{r}) dV.$$
(2)

In the presence of infinitesimal external strain  $\epsilon_{ij}^{ext}$ , elastic energy  $E_D$  can be represented by a Taylor series expansion:

$$E_D(\epsilon_{ij}^{ext}) = E_D(\epsilon_{ij}^{ext} = 0) + \left(\frac{\delta E_D}{\delta \epsilon_{ij}^{ext}}\right)_{\epsilon_{ij}^{ext} = 0} \epsilon_{ij}^{ext} + \cdots$$
(3)

The energy of elastic interaction between a defect and external strain field is
defined as [16]:

$$E = -P_{ij}\epsilon_{ij}^{ext},\tag{4}$$

where  $P_{ij}$  is the elastic dipole tensor of a defect. Comparing Eq. 3 and 4, we can identify the dipole tensor with

$$P_{ij} = -\left(\frac{\delta E_D}{\delta \epsilon_{ij}^{ext}}\right)_{\epsilon_{ij}^{ext}=0} = -\int_V \sigma_{ij}^D dV, \tag{5}$$

where  $\sigma_{ij}^D$  is the stress field resulting from the presence of a defect in the elastic medium.

In practice, calculations are not performed in an infinite medium. Infinite medium is simulated by applying periodic boundary conditions to a finite size simulation cell. This is equivalent to putting N identical defects in an infinite medium in the form of a lattice of defects, defined by the translation vectors of the simulation cell, where  $N \to \infty$ . We can write the total stress as a linear sum of contributions from all the identical periodically translated defects as [8],

$$\int_{V} \sigma_{ij}^{D} dV + \sum_{n \neq 0} \int_{V} \sigma_{ij}^{Im,n} dV = N \int_{V} \sigma_{ij}^{D} dV,$$
(6)

where  $\sigma_{ij}^{Im,n}$  is the stress field due to the  $n^{th}$  image of the defect. Dividing both sides of the above equation by N, we find

$$\int_{V} \sigma_{ij}^{D} dV = \frac{1}{N} \int_{V} \left( \sigma_{ij}^{D} + \sum_{n \neq 0} \sigma_{ij}^{Im,n} \right) dV = \int_{V_{cell}} \sigma_{ij} dV.$$
(7)

Therefore, the total stress induced by a defect integrated over infinite medium 154 equals the total stress of the defect plus all its images, integrated over a 155 simulation cell in a periodic boundary condition calculation. The proof is 156 based on the linear elasticity approximation stating that the total stress field 157 is a linear sum of stresses produced by the defect and all its images, and 158 on the fact that the stress field in a simulation cell is the same as in any 159 periodically translated cell. The simulation box used for defect calculation 160 needs to be of exactly the same shape and volume as in the corresponding 161 perfect lattice case, to mimic the infinite medium condition. 162

<sup>163</sup> Eq. 5 can now be written in term of macrostress  $\bar{\sigma}_{ij}$  developing in a <sup>164</sup> simulation cell under the PBCs, namely

$$P_{ij} = -\int_{V_{cell}} \sigma_{ij} dV = -V_{cell} \bar{\sigma}_{ij}.$$
(8)

The macrostress  $\bar{\sigma}_{ij}$  is the same as the average stress in the cell. We note that the volume integral may be ill-defined if the equation is applied to a discrete atomistic configuration. However, the same expression can be derived in the discrete atomistic approximation.

Provided that the total energy of the system depends only on atomic positions, such that  $E_D = E_D(\{\mathbf{R}_n\})$ , where  $\{\mathbf{R}_n\}$  is a set of coordinates, we can write

$$P_{ij} = -\left(\frac{\delta E_D}{\delta \epsilon_{ij}^{ext}}\right)_{\epsilon_{ij}^{ext}=0} = -\sum_{n,\alpha} \frac{\delta E_D}{\delta R_{n,\alpha}} \left(\frac{\delta R_{n,\alpha}}{\delta \epsilon_{ij}^{ext}}\right)_{\epsilon_{ij}^{ext}=0},\tag{9}$$

where *n* is the index of an atom and  $\alpha$  refers to a Cartesian coordinate. This first term in the right hand side is the component of force  $F_{n,\alpha}$  acting on the atoms. The second term can be obtained assuming that all the position vectors move in response to the applied external strain:

$$\mathbf{R} \to (\mathbf{I} + \boldsymbol{\epsilon})\mathbf{R},\tag{10}$$

176 which leads to

$$\left(\frac{\delta R_{n,\alpha}}{\delta \epsilon_{ij}^{ext}}\right)_{\epsilon_{ij}^{ext}=0} = R_{n,j}\delta_{\alpha i}.$$
(11)

<sup>177</sup> The dipole tensor then becomes

$$P_{ij} = \sum_{n} F_{n,i} R_{n,j} = -V_{cell} \bar{\sigma}_{ij}.$$
 (12)

This is the same formula for calculating dipole tensor as found using the 178 Kanzaki force method [16]. Interestingly, according to the Virial Theorem at 179 0K, the right hand side can also be written in terms of the macrostress. We 180 note that in a DFT calculation, the macrostress developing in a cell due to 181 the presence of a defect in it, is calculated as the variation of the total energy 182 as a function of the strain tensor. In both the continuum and discrete limits. 183 we arrive at the same equation for the dipole tensor. This equation relates 184 linear elasticity to both electronic and atomic scale simulations. 185

If the simulation cell used in the context of defect simulations has a different shape in comparison with the perfect lattice case, the case can be treated as if the simulation cell is subjected to external strain. The strain tensor describing the applied external strain  $\epsilon^{app}$ , given that  $\|\epsilon^{app}\| \ll 1$ , relates the perfect and deformed simulation cells as follows

$$\mathbf{V}^{perf}(\mathbf{I} + \boldsymbol{\epsilon}^{app}) = \mathbf{V}^{def},\tag{13}$$

<sup>191</sup> where **I** is the identity matrix,  $\mathbf{V}^{perf} = {\mathbf{L}_{1}^{perf}, \mathbf{L}_{2}^{perf}, \mathbf{L}_{3}^{perf}}$  is the matrix of <sup>192</sup> translation vectors of the perfect lattice cell and  $\mathbf{V}^{def} = {\mathbf{L}_{1}^{def}, \mathbf{L}_{2}^{def}, \mathbf{L}_{3}^{def}}$  is <sup>193</sup> the matrix of translation vectors of the cell containing a defect. Therefore <sup>194</sup> the strain tensor is simply

$$\boldsymbol{\epsilon}^{app} = (\mathbf{V}^{perf})^{-1} \mathbf{V}^{def} - \mathbf{I}.$$
 (14)

<sup>195</sup> Whenever applied strain exists, the dipole tensor should be corrected as <sup>196</sup> [6, 7, 9]

$$P_{ij} = V_{cell}(C_{ijkl}\epsilon_{kl}^{app} - \bar{\sigma}_{ij}).$$
(15)

There are other methods using which one can derive elastic dipole tensors from atomic scale simulation [16, 6, 18]. Varvenne and Clouet [7] concluded that only the residual stress method is tractable in the limit of small simulation cell, especially in the relation to *ab initio* calculations. Below we check the convergence of  $P_{ij}$ , and the effect of cell size on the elastic correction energy.

For a linear defect, such as a self-interstitial atom (SIA) crowdion defect, we can write [8]:

$$P_{ij} = C_{ijkl} \left( \Omega^{(1)} n_k n_l + \frac{\Omega^{(2)}}{3} \delta_{kl} \right)$$
(16)

where  $\mathbf{n} = (\cos \phi \sin \theta, \sin \phi \sin \theta, \cos \theta)$  is a unit vector characterizing the orientation of the axis of the defect, and  $\Omega^{(1)}$  and  $\Omega^{(2)}$  represent the relative contribution of the anisotropic and isotropic components to the relaxation volume of a defect, where the total relaxation volume of the defect is given by the sum

$$\Omega_{rel} = \Omega^{(1)} + \Omega^{(2)}. \tag{17}$$

Values of  $\Omega^{(1)}$  and  $\Omega^{(2)}$  can be obtained from *ab initio* calculations. This formula is used for analyzing the change in elastic correction energy assuming that a defect is able to rotate freely [8].

#### 213 2.2. Elastic correction energy

The formation energy of a defect equals [9]:

$$E_{def}^{F} = [E_{def}(N_{def}) - E^{app}] - \frac{N_{def}}{N_{perf}} E_{perf}(N_{perf}) - E_{el}^{corr},$$
(18)

where  $E_{def}$  is the energy of a simulation cell containing a defect,  $E_{perf}$  is the energy of a reference perfect lattice cell,  $N_{def}$  is the number of atoms in the cell containing a defect,  $N_{perf}$  is the number of atoms in a perfect lattice cell,  $E^{app}$  is the elastic energy due to the applied strain, and  $E_{el}^{corr}$  is the elastic correction energy due to the PBCs. The applied strain energy equals [6]:

$$E^{app} = \frac{V^{perf}}{2} C_{ijkl} \epsilon^{app}_{ij} \epsilon^{app}_{kl} - P_{ij} \epsilon^{app}_{ij}, \qquad (19)$$

where  $V^{ref}$  is the volume of the simulation cell. We neglect the change of volume due to deformation assuming small applied strain. The first term in equation (19) accounts for the elastic energy associated with the deformation of the simulation cell. The second term is the result of interaction between the defect and applied strain.

The elastic correction energy  $E_{el}^{corr}$  is a term resulting from the periodic supercell effect. It contains two parts

$$E_{el}^{corr} = E_{DD} + E_{strain}^{corr}.$$
 (20)

 $E_{DD}$  is the energy due to elastic interaction between a defect and its periodic images, represented by elastic dipole-dipole terms.  $E_{strain}^{corr}$  is the self-strain correction energy. Adopting the far-field elasticity approximation, the regularized elastic interaction energy  $E_{DD}$  can be written in terms of elastic dipole tensor and anisotropic elastic Green's function [19, 6, 7, 8], where

$$E_{DD} = E_{DD}^{total} + E_{DD}^{corr}.$$
 (21)

<sup>232</sup> The first term

$$E_{DD}^{total} = \frac{1}{2} \sum_{n \neq 0} P_{ij} P_{kl} \frac{\partial}{\partial x_j} \frac{\partial}{\partial x_l} G_{ik}(\mathbf{R}_n)$$
(22)

is a sum of pairwise elastic interactions between a defect and its periodic images situated at  $\mathbf{R}_n$ . The sum is conditionally convergent. The second term

$$E_{DD}^{corr} = -\frac{1}{2V_{cell}} \sum_{n \neq 0} \int_{V_{cell}} P_{ij} P_{kl} \frac{\partial}{\partial x_j} \frac{\partial}{\partial x_l} G_{ik} (\mathbf{R}_n - \mathbf{r}) d^3r$$
(23)

regularizes the strain produced by the periodic images and ensures the absolute convergence of sum (22).

<sup>238</sup> The self-strain correction energy is

$$E_{strain}^{corr} = -\frac{1}{2} P_{ij} \left( -\bar{\epsilon}_{ij}^D \right) = \frac{1}{2V_{cell}} \int_{V_{cell}} P_{ij} \epsilon_{ij}^D(\mathbf{r}) d^3 r.$$
(24)

As we only need to correct the linear elastic part of the strain field of the defect, one can apply the far-field approximation again, namely

$$E_{strain}^{corr} = -\frac{1}{2V_{cell}} \int_{V_{cell}} P_{ij} P_{kl} \frac{\partial}{\partial x_j} \frac{\partial}{\partial x_l} G_{ik}(\mathbf{r}) d^3 r.$$
(25)

This term corrects the total energy for the effect of elastic strain produced by the defect itself. Eq. (25) has the form similar to Eq. (23), and corresponds to the first term n = 0 in the series.

In practice, Eq. (23) and (25) can be represented by surface integrals through the use of the divergence theorem [20], namely

$$\int_{V_{cell}} P_{kl} \frac{\partial}{\partial x_j} \frac{\partial}{\partial x_l} G_{ik}(\mathbf{r}) d^3 r = \oint_{S_{cell}} P_{k\alpha} \frac{\partial}{\partial x_j} G_{ik}(\mathbf{r}) n_{\alpha} dS.$$
(26)

Here **n** is the unit vector of external surface normal, and index  $\alpha$  refers a Cartesian component of this vector. Calculating the first derivative of elastic Green's function is numerically more expedient that the second derivative, and the same applies to the calculation of surface integrals versus volume integrals. Elastic Green's function, and its first and second derivatives can be calculated numerically following Barnett's approach [21].

#### 252 3. Algorithm

It is not feasible to calculate  $E_{DD}^{total}$  and  $E_{DD}^{corr}$  by adding up an infinite number of terms in the series. Provided that we take the same number of terms in both series, the sum of them,  $E_{DD}$ , converges at a large cutoff distance [8]. Calculating  $E_{DD}^{total}$  is trivial, since we can evaluate the second derivative of elastic Green's function numerically. The calculation of  $E_{DD}^{corr}$  is somewhat more involved as it requires calculating integrals over the surface of the simulation cell, see Eq. 26.

A simulation cell involving PBCs usually has six surfaces. Generally, we need to consider a surface integral over a rhombohedral cell. For an arbitrary function F, the surface integral of a rhomboid in three dimensional system of coordinates can be written as

$$\int_{S} F(\mathbf{r}(u,v)) dS = \int_{-1}^{1} \int_{-1}^{1} F(\mathbf{r}(u,v)) J(u,v) du dv$$
(27)

<sup>264</sup> where

$$J(u,v) = \left\| \frac{\partial \mathbf{r}}{\partial u} \times \frac{\partial \mathbf{r}}{\partial v} \right\|$$
(28)

is the transformation Jacobian. The position vector  $\mathbf{r}$  is a function of u and v in terms of the translation vectors of the simulation cell. For example, the position vector at the top and bottom surfaces of a box is

$$\mathbf{r} = \frac{u}{2}\mathbf{L}_x + \frac{v}{2}\mathbf{L}_y \pm \frac{1}{2}\mathbf{L}_z,\tag{29}$$

where the + and - signs in the last term correspond to the top and bottom surfaces, respectively. The Jacobian for both the top and bottom surfaces is now

$$J(u,v) = \frac{1}{4} \left\| \mathbf{L}_x \times \mathbf{L}_y \right\|.$$
(30)

The Jacobian for the other four surfaces can be evaluated in a similar way.
Integration from -1 to 1 is performed numerically using the nine point
Gaussian quadrature method. In the two dimensional case, the double integration is performed in a nested manner, namely

$$\int_{-1}^{1} \int_{-1}^{1} f(u, v) du dv \approx \sum_{i} \sum_{j} w_{i} w_{j} f(u_{i}, v_{j})$$
(31)

where  $w_i$  and  $w_j$  are the weights with respect to  $u_i$  and  $v_j$ . This fully defines the numerical procedure required for evaluting the surface integral in Eq. (26). A test involving eleven point Gaussian quadrature integration was also performed, and procudes the same result up to four decimal places [8].

We have verified our calculations of  $E_{DD}$  using summation over cubic, 279 spherical and ellipsoidal summation volumes [8], increasing the magnitude of 280 the cut-off distance, and found that the results were absolutely convergent in 281 all cases. Considering the balance between efficiency and accuracy, we chose 282 to use spherical neighbourhoods with the cutoff radius of  $10 + \delta$  times trans-283 lation vectors, where the magnitude of  $\delta$  is small. Our results were verified 284 numerically against numerical results computed using ANETO [6], which is a 285 FORTRAN program developed independently by Varvenne *et al.* for a simi-286 lar purpose. The authors of Ref. [6] attribute their methodology to Cai et al. 287 [22], who developed it for correcting elastic interactions between dislocations 288 in two dimensions, using an electrostatic analogy. No electrostatic analogy 289 was involved in the derivation of equations given in the preceding section of 290 this paper. 291

#### <sup>292</sup> 4. Compilation of the program

CANALIE is a code written in C++. It can be compiled using any
modern C++ compiler, including Intel and GNU compilers. No linking to
external libraries is required. The code can be compiled in two different ways
for two different purposes. The first one is for general *ab initio* calculations.
Using g++, one can compile CANALIE using the following command line

<sup>298</sup> \$ g++ -DABINITIO -DSTRESSeV -o calanie CALANIE\_2.0.cpp

299 OT

#### <sup>300</sup> \$g++-DABINITIO-DSTRESSGPa-o calanie CALANIE\_2.0.cpp

Option -DABINITIO defines the word ABINITIO in the code, such that 301 the program is compiled for the purpose of correcting the elastic energy 302 and obtaining the dipole tensor from the output of a general purpose ab303 *initio* program. Option -DSTRESSeV means that stresses in the input file 304 should be given in eV units. In other words, the input stresses are not the 305 macro-stresses, but rather the macro-stresses multiplied by the cell volume. 306 If one uses VASP [23, 24, 25, 26], the values are given in the line "Total" 307 of the "OUTCAR" file. On the other hand, one can use a more general 308 option -DSTRESSGPa. The stresses in the input file should then be given 309 as the residual stresses, and should have the units of GPa. The sign of 310 stresses follows the convention adopted in VASP. Positive stress means that 311 the simulation cell attempts to expand. 312

The second compilation option is needed for analyzing the relative elastic effect assuming that a linear defect can be rotated. It can be compiled using the command

<sup>316</sup> \$ g++ -DORIENTATION -o calanie CALANIE\_2.0.cpp

This command compilation is required for analyzing changes in elastic correction energy of a defect assuming that it can rotate freely, according to Eq. 16. This enables assessing the stability of a defect under the influence of stresses developing in the supercell under PBCs. Application of this compilation option was illustrated in our earlier work [8].

#### 322 5. Inputs and outputs

CALANIE requires two input files. They are *input\_data* and *input\_elastic*. These files need to be located in the same directory for executing CALANIE. Both of them are ASCII files.

When we use option -DABINITIO, in the *input\_data* file we need to specify the translation vectors, the linear scaling factor, and the residual stresses in the perfect cell and in the cell containing a defect. They should be specified using the following format

330	box_ref_11 ???
331	box_ref_12 ???
332	box_ref_13 ???
333	box_ref_21 ???
334	box_ref_22 ???
335	box_ref_23 ???
336	box_ref_31 ???
337	box_ref_32 ???
338	box_ref_33 ???
339	a_lattice_ref ???
340	
341	box_def_11 ???
342	:
343	box_def_33 ???
344	a_lattice_def ???
345	
346	stress11_ref ???
347	:
348	stress33_ref ???
349	
350	stress11_def ???
351	:
352	stress33_def ???
353	

The numerical value that follows a keyword is the input value, the position of which is indicated by ??? above. Keywords **box\_ref\_** $\alpha\beta$  and **box\_def\_** $\alpha\beta$ are the translation vectors of the perfect reference cell and the cell containing a defect, and  $\alpha, \beta = 1, 2, 3$ . Keywords **a\_lattice\_ref** and **a\_lattice\_def** are linear scaling factors. Keywords  $\operatorname{stress}\alpha\beta_{-}\operatorname{ref}$  and  $\operatorname{stress}\alpha\beta_{-}\operatorname{def}$  are the residual stresses in the reference cell and in a cell containing a defect. One and only one value should be given. All the nine matrix elements for the translation vectors and residual stresses are required.

In the *input\_elastic* file, the first two lines are comment lines. The third to eighth lines contain values of elastic constants in the Voigt notation  $C_{ij}$ , in GPa units, followed by the compliance constants  $S_{ij}$ , also in the Voigt notation, in GPa<sup>-1</sup> units. The input should appear as follows

366	# comments
367	#comments
368	$C_{11} C_{12} C_{13} C_{14} C_{15} C_{16}$
369	$C_{21} C_{22} C_{23} C_{24} C_{25} C_{26}$
370	$C_{31} C_{32} C_{33} C_{34} C_{35} C_{36}$
371	$C_{41} C_{42} C_{43} C_{44} C_{45} C_{46}$
372	$C_{51} C_{52} C_{53} C_{54} C_{55} C_{56}$
373	$C_{61} C_{62} C_{63} C_{64} C_{65} C_{66}$
374	$S_{11} S_{12} S_{13} S_{14} S_{15} S_{16}$
375	$S_{21} S_{22} S_{23} S_{24} S_{25} S_{26}$
376	$S_{31} S_{32} S_{33} S_{34} S_{35} S_{36}$
377	$S_{41} \ S_{42} \ S_{43} \ S_{44} \ S_{45} \ S_{46}$
378	$S_{51} S_{52} S_{53} S_{54} S_{55} S_{56}$
379	$S_{61} S_{62} S_{63} S_{64} S_{65} S_{66}$

Once both input files *input\_data* and *input\_elastic* are available, the program can be run from the same directory by executing the command

382 \$ ./calanie

We provide a simple python script  $make\_input\_elastic.py$  to help generate  $input\_elastic$ . One needs to provide a file with the name  $input\_elastic\_Cij$  with only the first eight lines of  $input\_elastic$ . By running  $make\_input\_elastic.py$ , one generates file  $input\_elastic$  with the required values of  $S_{ij}$ . Sample files with names  $input\_data\_2$ ,  $input\_elastic$  and  $input\_elastic\_Cij$  are included in the distribution of CALANIE.

When using option -DORIENTATION, in *input\_data* we only need to specify the translation vectors and linear scaling factor for the reference cell. We also need the values of  $\Omega^{(1)}$  and  $\Omega^{(2)}$  through the keywords of **Omega1** and **Omega2** in Å<sup>3</sup> units. A sample file named *input\_data\_1* illustrates this

	No. of atoms	Approx. cell size	k-points
Vac	107	3x3x3	4x4x4
$\langle 100 \rangle d$	145	3x3x4	4x4x3
Octa	145	3x3x4	4x4x3
$\langle 110 \rangle c$	193	3x4x4	4x3x3
$\langle 110 \rangle d$	193	3x4x4	4x3x3

Table 1: The number of atoms, approximate cell size (in the units of cubic unit cell size), and the k-point mesh that were used in the calculations of vacancy,  $\langle 100 \rangle$  dumbbell, octahedral site interstitial,  $\langle 110 \rangle$  crowdion, and  $\langle 110 \rangle$  dumbbell defects in FCC gold.

<sup>393</sup> part of input. The *input\_elastic* file is the same as in the previous case. <sup>394</sup> However, when we run the program, we need to specify the orientation of a <sup>395</sup> defect in terms of  $\theta$  and  $\phi$ , namely

396 \$./calanie  $\theta \phi$ 

The dipole tensor of the defect can be calculated using Eq. 16, followed by the calculation of its elastic correction energy.

There is no output file format associated with either option. Outputs are printed out directly. Values of  $P_{ij}$ ,  $E^{app}$ ,  $E^{total}_{DD}$ ,  $E^{corr}_{DD}$ ,  $E_{DD}$ ,  $E^{corr}_{strain}$ , and  $E^{corr}_{el}$  are computed and displayed. The relaxation volume tensor  $\Omega_{ij}$ and relaxation volume  $\Omega_{rel}$  are also evaluated and printed out according to equations  $\Omega_{ij} = S_{ijkl}P_{kl}$  and  $\Omega_{rel} = \text{Tr}(\Omega_{ij})$ .

#### 404 6. Applications

#### 405 6.1. Ab initio calculations: Point defects in FCC gold

Elastic correction can be readily applied in the context of a calculation of formation and migration energies of point defects. We have applied CALANIE to improve the quality of *ab initio* data on defect energies in FCC gold, which were partially described in a study by Hofmann *et al.* [27]. The calculations were performed for vacancy and self-interstitial atom (SIA) defects, where the latter included a  $\langle 100 \rangle$  dumbbell, an octahedral site interstitial, a  $\langle 110 \rangle$  crowdion, and a  $\langle 110 \rangle$  dumbbell.

All the *ab initio* density functional theory (DFT) calculations were performed using Vienna Ab initio Simulation Package (VASP) [23, 24, 25, 26]. We used the revised-TPSS exchange-correlation functional [28, 29]. The spinorbit coupling was also included, to account for the band splitting and shape

	$E_{def}$	$E_{perf}$	$E^{app}$	$E_{el}^{corr}$	$E_{def}^F$	$ \begin{array}{c} E_{def}^{F} \\ \text{(no corr)} \end{array} $
Vac	4056.141572	4093.103600	-0.010717	0.00848	0.939	0.937
$\langle 100 \rangle d$	5499.210885	5457.464770	-0.273714	0.18303	3.938	3.847
Octa	5499.380148	5457.464770	-0.285801	0.19697	4.105	4.016
$\langle 110 \rangle c$	7318.341711	7276.601601	-0.275946	0.15802	3.959	3.841
$\langle 110 \rangle d$	7318.342569	7276.601601	-0.275557	0.15747	3.960	3.842

Table 2: The total energy  $E_{def}$  of a simulation box containing a defect, the total energy  $E_{perf}$  of a perfect lattice simulation cell, the applied strain energy  $E^{app}$ , the elastic correction energy  $E_{el}^{corr}$ , and the formation energy  $E_{def}^{F}$  of a vacancy, a  $\langle 100 \rangle$  dumbbell, an octahedral site interstitial, a  $\langle 110 \rangle$  crowdion, and a  $\langle 110 \rangle$  dumbbell in FCC gold. The value of  $E_{def}^{F}$  with no elastic correction, corresponding to  $E^{app} = 0$  and  $E_{el}^{corr} = 0$ , is also given for comparison. All the values are given in eV units.

	$P_{11}$	$P_{22}$	$P_{33}$	$P_{12}$	$P_{23}$	$P_{31}$
Vac	-6.760	-6.760	-6.760	0.000	0.000	0.000
$\langle 100 \rangle d$	36.667	39.612	39.612	0.000	0.000	0.000
Octa	39.371	39.984	39.984	0.000	0.000	0.000
$\langle 110 \rangle c$	38.856	38.856	41.084	11.199	0.000	0.000
$\langle 110 \rangle d$	38.742	38.742	41.332	11.155	0.000	0.000

Table 3: Elastic dipole tensor  $P_{ij}$ , in eV units, computed for a vacancy, a  $\langle 100 \rangle$  dumbbell, an octahedral site interstitial, an  $\langle 110 \rangle$  crowdion, and a  $\langle 110 \rangle$  dumbbell in FCC gold.

	$\Omega_{11}$	$\Omega_{22}$	$\Omega_{33}$	$\Omega_{12}$	$\Omega_{23}$	$\Omega_{31}$	$\Omega_{rel}$
Vac	-0.117	-0.117	-0.117	0.000	0.000	0.000	-0.351
$\langle 100 \rangle d$	0.231	0.888	0.888	0.000	0.000	0.000	2.008
Octa	0.598	0.735	0.735	0.000	0.000	0.000	2.068
$\langle 110 \rangle c$	0.520	0.520	1.018	1.062	0.000	0.000	2.058
$\langle 110 \rangle d$	0.494	0.494	1.072	1.057	0.000	0.000	2.059

Table 4: Relaxation volume tensor  $\Omega_{ij}$  and relaxation volume  $\Omega_{rel}$ , in atomic volume units, computed for a vacancy, a  $\langle 100 \rangle$  dumbbell, an octahedral site interstitial, a  $\langle 110 \rangle$  crowdion, and a  $\langle 110 \rangle$  dumbbell in FCC gold.

<sup>417</sup> modification of the 5*d* bands [30, 31, 32]. The plane wave energy cut-off is <sup>418</sup> 450 eV for the 11 valence electrons included in the calculation. Different <sup>419</sup> sizes of simulation cells were used for different defects. The corresponding <sup>420</sup> box sizes and k-point meshes are given in Table 1. All the simulation boxes <sup>421</sup> were relaxed to the stress-free condition, with residual forces lower than 0.01 <sup>422</sup> eV/Å. Formation energies were calculated using Eq. 18 with respect to a <sup>423</sup> perfect crystal, using a similar cell size and the same k-point mesh.

Elastic constants are also required for calculating  $E^{app}$  and  $E^{corr}_{el}$ . They were calculated using the Le Page and Saxe method [33], using a 4-atom cubic cell. From *ab initio* calculations we obtained  $C_{11} = 210.55$ GPa,  $C_{12} =$ 168.11GPa and  $C_{44} = 49.96$ GPa. These values are compatible with the low temperature experimental values, which are  $C_{11} = 201.63$ GPa,  $C_{12} =$ 169.67GPa and  $C_{44} = 45.44$ GPa [34]. The calculated lattice constant is 430 4.075Å, whereas the experimental value is 4.07833Å [35].

The corrected defect formation energies  $E_{def}^F$ , applied strain energies  $E^{app}$ , 431 elastic correction energies  $E_{el}^{corr}$ , and the formation energy of defects with no 432 correction applied, that is ignoring  $E^{app}$  and  $E^{corr}_{el}$ , are given in Table 2. 433 It shows that a  $\langle 100 \rangle$  dumbbell has the lowest formation energy, whereas a 434  $\langle 110 \rangle$  crowdion has the lowest formation energy if the elastic correction is 435 not included. However, we should note that the energy difference between a 436  $\langle 100 \rangle$  dumbbell, a  $\langle 110 \rangle$  crowdion and a  $\langle 110 \rangle$  dumbbell is very small. Since 437 the accuracy of a DFT calculation is in the meV range, it is hard to draw 438 a definitive conclusion about the structure of the most stable SIA defect 439 configuration in gold. 440

Elements of elastic dipole tensors  $P_{ij}$ , in eV units, are given in Table 441 3, whereas the elements of the relaxation volume tensor  $\Omega_{ij}$  and the total 442 relaxation volume  $\Omega_{rel}$ , in atomic volume units, are given in Table 4. We 443 note that their values are correlated with the symmetry of a particular defect. 444 Indeed, the calculated values of  $P_{ij}$  and  $\Omega_{ij}$  might be more significant than the 445 calculated values of the elastic correction terms. One can readily use them 446 to evaluate the strength of defect-defect interactions through linear elasticity 447 theory [5, 6, 7, 8, 9], and even apply it to examine the stress profile of an 448 irradiated component on a macroscopic scale, if the distribution of defects is 440 defined [17]. 450

Elastic correction can also be applied to non-equilibrium configurations. For example, it can be applied to the atomic configurations describing the migration pathway of a defect. We performed a nudged elastic band calculation [36, 37] of vacancy migration in gold, where seven NEB images were



Figure 1: Variation of the formation energy of a vacancy during its transition from an equilibrium position to a nearest neighbour equilibrium position. A small difference can be observed between the cases studied with and without applying the elastic correction.



Figure 2: Elastic dipole tensor of a vacancy moving along a migration pathway in the y-z plane. Owing to the symmetry of the defect,  $P_{22} = P_{33}$  and  $P_{12} = P_{31} = 0$ .

used. A vacancy hops from an equilibrium position to the nearest neighbour equilibrium position in the y-z plane. Fig. 1 shows the change in the formation energy with and without the elastic energy correction. The computed migration energy agrees well with experimental value of  $0.71 \pm 0.05 \text{eV}$  [35]. The effect of applying the elastic correction is not prominent in this case, as the stress field induced in the lattice by a vacancy is relatively weak.

<sup>461</sup> On the order hand, we observe a change in  $P_{ij}$  during the transition, illus-<sup>462</sup> trated in Fig. 2, which can give rise to effects of anisotropic diffusion under <sup>463</sup> external stress, or the stress induced by other defects [38]. The anisotropic <sup>464</sup> diffusion tensor in linear approximation of a spatially slow varying external <sup>465</sup> strain field  $\epsilon_{ij}(\mathbf{R})$  can be written, following Dederichs and Schroeder [39], as

$$D_{ij}(\mathbf{R}) = \frac{1}{2} \sum_{h} \lambda_h r_i^h r_j^h \exp\left(\frac{\epsilon_{kl}(\mathbf{R})(P_{kl}^{sd,h} - P_{kl}^{eq})}{k_B T}\right),\tag{32}$$

where *h* refers to a possible hopping site,  $\lambda_h = \nu_0 \exp(-E_D^{M,h}/k_BT)$  is the atomic jump frequency,  $\nu_0$  is the attempt frequency,  $E_D^{M,h}$  is the migration barrier,  $r_i^h$  is a Cartesian component of the hopping direction vector,  $P_{kl}^{sd,h}$ and  $P_{kl}^{eq}$  are the elastic dipole tensors at the saddle point and at an equilibrium position. The value of  $D_{ij}$  for a given value of strain can be evaluated using the data given here. Anisotropic diffusion of point defects under applied stress induced by a screw dislocation has been explored by Sivak and Sivak [40] in fcc copper using kinetic Monte Carlo simulations.

#### 474 6.2. Molecular statics: Dislocation loop in tungsten

Elastic field of a mesoscopic defect is much stronger than that of a point 475 defect. Elastic correction is also larger for a defect of larger size in a small 476 simulation box. For example, an *ab initio* calculation is usually limited to a 477 few hundred atoms. The formalism developed in this paper can be applied to 478 any localized defect irrespective to its structure. If the elastic dipole tensor 479  $P_{ij}$  of the defect is known, one can use it to compute the corrected defect 480 formation energy  $E_{def}^F$  using Eq. 18, provided that the strain field at the 481 surface of a simulation box is approximated by linear elasticity. We would 482 like to examine the convergence of the  $P_{ij}$  and  $E_{def}^F$  of mesoscopic scale defects 483 as a function of simulation cell size and simulation conditions. 484

We have investigated the points using molecular statics. Molecular static allows us to do highly accurate calculations using very large simulation cells



Figure 3: Atomic configuration of (left) a circular  $\frac{1}{2}\langle 111 \rangle$  and (right) a square  $\langle 100 \rangle$  self-interstitial atom loop. Both loops contain 61 self-interstitial atoms. Bulk atoms were filtered out according to the centre of symmetry parameter criterion.

within reasonable computation time. We used the Mason-Nguyen-Manh-487 Becquart (MNB) [41] potential for tungsten. The calculated elastic con-488 stants for this potential are  $C_{11} = 526.83$ GPa,  $C_{12} = 205.28$ GPa, and 489  $C_{44} = 160.63$  GPa. All the calculations were performed using LAMMPS [42]. 490 Atomic relaxations were performed using the conjugate gradient method. We 491 have investigated circular  $\frac{1}{2}\langle 111 \rangle$  self-interstital atom (SIA) loops containing 492 7, 13, 19, 37, 55 and 61 atoms, and square (100) SIA loops with 5, 13, 25, 493 41 and 61 atoms, using simulation cells of varying size containing from 2,000 494 to 1 million atoms. Two sets of calculations were performed. In one set, 495 the shape and volume of the simulation cell remained fixed and the same as 496 in the perfect lattice case. In the other set, the cell was permitted relax to 497 a stress-free condition. The loop structure of a circular  $\frac{1}{2}\langle 111 \rangle$  and square 498 (100) loop with 61 atoms are shown in Fig. 3. They were generated using 499 AtomEye [43], where bulk atoms were filtered using the centre of symmetry 500 parameter criterion. 501

Fig. 4 shows elements of the elastic dipole tensor of  $\frac{1}{2}\langle 111\rangle$  SIA loops 502 plotted as functions of the simulation cell size. Due to the symmetry of the 503 defect, values of diagonal terms are all the same and labelled  $P_{\alpha\alpha}$ , whereas 504 the off-diagonal terms also have the same values and are labelled  $P_{\alpha\beta}$ . We 505 see that both the fixed cell and stress-free condition calculations converge to 506 the same value if the simulation box is large enough. Under the stress-free 507 condition, when the simulation cell size is in the range of  $10 \times 10 \times 10$  and 508  $11 \times 11 \times 11$  unit cells, the cells containing 55 and 61 atoms loops deform 509



Figure 4: Elastic dipole tensors of  $\frac{1}{2}\langle 111 \rangle$  self-interstitial atom loops containing 7, 13, 19, 37, 55, and 61 atoms as functions of the simulation cell size.  $P_{\alpha\alpha}$  are the diagonal terms, whereas  $P_{\alpha\beta}$  are the off-diagonal terms. Elements of the elastic dipole tensor are computed using the condition that the simulation cell shape was fixed to match the perfect lattice case, or allowed to relax to a stress-free condition.



Figure 5: Formation energy  $E_{def}^F$  of  $\frac{1}{2}\langle 111 \rangle$  self-interstitial atom loops containing 7, 13, 19, 37, 55, and 61 atoms shown as a function of the simulation cell size. The  $E_{def}^F$  is calculated with elastic correction applied, i.e. using Eq. 18, or without the correction, i.e. ignoring the  $E^{app}$  and  $E_{el}^{corr}$ . Both are calculated under the condition that the simulation cell shape was fixed to match the perfect lattice case, or was allowed to relax to a stress-free condition.



Figure 6: Elements of elastic dipole tensors of  $\langle 100 \rangle$  self-interstitial atom loops containing 5, 13, 25, 41, and 61 atoms plotted as a function of ten simulation cell size. The offdiagonal terms of the dipole tensor vanish because of symmetry. The elastic dipole tensor is calculated under the condition that the simulation box shape was fixed to match the perfect lattice case, or was allowed to relax to a stress-free condition.



Figure 7: Formation energy  $E_{def}^F$  of  $\langle 100 \rangle$  self-interstitial atom loops containing 5, 13, 25, 41, and 61 atoms shown as a function of the simulation cell size. Values of  $E_{def}^F$  were calculated with elastic correction applied, i.e. using Eq. 18, or with no correction, i.e. ignoring  $E^{app}$  and  $E_{el}^{corr}$ . Both were calculated under the condition that the simulation box shape was fixed to match the perfect lattice case, or was allowed to relax to a stress-free condition.

significantly. The calculated values of  $P_{ij}$  do not reflect the correct symmetry of a  $\frac{1}{2}\langle 111 \rangle$  SIA loop type, so we discarded these data.

Fig. 5 shows the corrected formation energy calculated using the data shown in Fig. 4. We note that the elastic correction converges well in the limit of large simulation box. At the same time, we see that although the fixed cell and stress-free condition calculations suggest different values prior to the application of elastic correction, their values become comparable when this correction is applied. For mesoscopic scale loops, e.g. a 61 atom loop, the difference can be fairly large if the correction is not applied.

Fig. 6 and 7 show elements of the dipole tensor and formation energy 519 of (100) loops as functions of the cell size. Due to symmetry, we know that 520 the elements of dipole tensor  $P_{11} = P_{22}, P_{33} \neq 0$ , and that the off-diagonal 521 elements all vanish. We observe a similar behaviour for (100) loops as for 522  $\frac{1}{2}\langle 111\rangle$  loops. The error in  $P_{ij}$  becomes larger when the size of the defect 523 becomes comparable to the size of the simulation box. This is a consequence 524 of the fact that the derivation of the dipole tensor formalism is based on the 525 linear elasticity approximation. 526

When the size of the simulation cell is small, the deformation of the lattice 527 near the surface of the cell due to a defect may become large and hence non-528 linear. This makes the values of  $P_{ij}$  computed in the linear elasticity theory 529 approximation inaccurate. Nevertheless, it still help correct the formation 530 energy for various simulation cell conditions, such as in the two limiting 531 cases of the fixed box and stress-free conditions. This enables calculating 532 the formation energy of a relatively large size defect using a relatively small 533 simulation cell with confidence, which is important especially in the context 534 of an *ab initio* calculation where the cost of computation is high. 535

#### 536 7. Conclusion

In this study, we presented the fundamental theory, algorithms and nu-537 merical implementation of computer program CALANIE, intended for the 538 evaluation of anisotropic elastic interaction energy under periodic boundary 539 conditions (PBCs). The theory is based on the linear elasticity approxi-540 mation. The elastic interaction of a defect with its periodic images can be 541 approximated and evaluated using the elastic dipole and elastic Green's func-542 tion formalism. The elements of elastic dipole tensor can be computed in the 543 same electronic or atomic scale simulation as the formation energy of the de-544 fect. Elastic Green's function and its first and second derivatives can also be 545

calculated numerically if the values of elastic constants are known. Examples
with input files are given. Compilation of CALANIE can be performed using
any modern C++ compiler.

Applications of the program are illustrated using two case studies as ex-549 amples. One example involves *ab initio* calculations of point defects in FCC 550 gold. We show that elastic correction can be applied not only to the equilib-551 rium, but also to non-equilibrium configurations. Other applications involve 552 relatively large, mesoscopic scale defects. We investigate the convergence of 553 calculations of elements of dipole tensors and formation energies in the large 554 simulation cell limit. We show that the elastic correction treatment can im-555 prove the quality of evaluation of the formation energy even in the limit 556 where the size of the defect is comparable with the size of the simulation cell. 557

#### 558 Acknowledgement

This work has been carried out within the framework of the EUROFusion Consortium and has received funding from the Euratom research and training programme 2014-2018 and 2019-2020 under grant agreement No. 633053 and from the RCUK Energy Programme [grant No. EP/I501045]. To obtain further information on the data and models underlying the paper please contact PublicationsManager@ccfe.ac.uk. The views and opinions expressed herein do not necessarily reflect those of the European Commission.

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